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प्लाज्मा अनुसंधान संस्थान INSTITUTE FOR PLASMA RESEARCH परमाण् ऊर्जा विभाग, भारत सरकार का एक सहायता



प्राप्त संस्थान

An Aided Institute of Department of Atomic Energy, **Government of India**

इन्दिरा पुल के पास, भाट, गांधीनगर - 382 428 भारत

द्रभाष: (079) 2396 2020/2021/2028

फैक्स: 91-079-23962277

वेब: www.ipr.res.in

NEAR INDIRA BRIDGE, BHAT

DIST. GANDHINAGAR - 382 428 (INDIA) Phone: (079) 2396 2020/2021/2028

Fax : 91-079-23962277

Web: www.ipr.res.in

ENQUIRY

ENQUIRY NO : IPR/EQL/19-20/004

: 04-04-2019 Date

: 25-04-2019 by 1:00 PM IST Due on

Please send your offer in sealed envelope specifying Enquiry No, Date & Due Date, ALONG WITH your credentials for the following items:

Important Note:

Please note that e-mail quotations are not acceptable however you may send your queries (if any) to localpurchase@ipr.res.in

Please ensure your sealed quotation reaches this office not later than above mentioned due date and time.

Kindly go through the following documents properly before quoting which are available on the IPR web portal i.e., http://www.ipr.res.in/documents/tender_terms.html / attached herewith.

- 1) Instructions to the bidders & Terms and conditions (refer Form No: IPR-LP-01.V4)
- 2) Bidding format

GST for Goods and Services (IGST/CGST/SGST TAX BENEFITS): Please refer clause no: 8 of Form No: IPR-LP-01.V4

QUOTATION SHOULD BE ADDRESSED TO PURCHASE OFFICER ONLY

Sr No	Description	Quantity
1	IC Log112	20.0 Nos.
2	MOSFET IRF540	20.0 Nos.
3	IC CA3140	20.0 Nos.
4	IC UC3843	20.0 Nos.

5	Transistor 2N3906	20.0 Nos.
6	Zener 50V, 1W	20.0 Nos.
7	Zener 30V, 1W	20.0 Nos.
8	8. DPST Relay- NO	20.0 Nos.
	Coil: 24V,	
	Contact capacity: 25 A	
	PCB terminals	
	Equivalent: OMRAN model G7L-2A-P	
9	9. PCB mounting for relay in S/N 8	10.0 Nos.

Note: Note: (1) Unsigned quotations are not acceptable.

Quotation should be submitted duly signed on ALL PAGES

invariably

(2) TDS as per CGST Act : As per provisions of section No. 51 of the CGST Act 2017, TDS @ 2% (IGST 2% or CGST 1% and SGST 1%) will be deducted while making

payment to the suppliers where total value of

orders/contracts/work orders exceeds Rs. 2.5 Lakhs, in

the event of order in Indian Rupees

Encl: As Per Attachment

Sd/-

Mr. D. Ramesh Purchase Officer-II

Information to Vendors: We are working towards a single platform for our future requirement. Hence, please refer IPR website i.e, http://www.ipr.res.in/documents/tenderseng.html for our future requirement.

Compliance Sheet

Various Electronics Components:

S/N	Entity	IPR Specification	Vendor Specification
1	IC log112A		
	Packaging:	SO-14	
	Supply Voltage, V+ to V-	±18V	9 /
	Inputs	±18V	
	Input Current	±10mA	
	Output Short-Circuit	Continuous	2286350
	Current Continuous		
	Storage Temperature	-55°C to +125°C	
	Operating Temperature –	40°C to +85°C	
2	IRF 540 MOSFET		
-	Packaging	TO-220AB	
	Drain-Source Volt (Vds)	100V	
for my	Drain-Gate Volt (Vdg)	100V	
1	Gate-Source Volt (Vgs)	20V	Construction of the second
	Drain Current (Id)	30A	- State myoles
	Power Dissipation (Ptot)	150W	
	Type	N-Channel	
3	IC CA3140	1 Chamier	
3	Packaging:	PDIP	
1	Supply Voltage, V+ to V-	±18V	
-	Differential mode Input	8V	
â _l o	Voltage	O V	
	DC Input Voltage	V+ +8V to V0.5V	
	Input Current	1mA	
	Output Short-Circuit	Indefinite	
	Duration		
	Operating Temperature	-55°C to +125°C	
	Junction Temperature	+150°C	
	Lead Temperature	+300°C	
	(soldering, 10s)		
	Storage Temperature	−65°C to +125°C	
4	IC UC3843		The state of the s
-	Packaging:	DIP	
1 2 3 19	UVLO Start	8.5 V	
	Maximum Duty Cycle:	<100%	
	Start Up Current	<1 mA	
	Operating Frequency:	up to 500KHz	
5	Transistor 2N3906		er tallen, med en
	Packaging:	TO-92	
	MAXIMUM RATINGS		
	Collector – Emitter Voltage	40 V dc	
	Collector – Base Voltage	40 V dc \(\frac{1}{2} \)	
	Emitter – Base Voltage	5.0 V dc	
	Collector Current –	200mA dc	

	Continuous	711 111111111	
	Total Device Dissipation@ TA= 25°C	625 mW	ry commenced some
	Derate above 25°C	5.0 mW/°C	44.50.9
	Operating and Storage Junction Temperature Range	-55 to +150°C	Litani 74
6	Zener 50V, 1 watt		
	Packaging	DO-41	
	Tolerance	±2%	
7	Zener 30V, 1 watt		
	Packaging	DO-41	
	Tolerance	±2%	
8	DPST Relay- NO		
* 60	Coil	24V	
9	Contact capacity:	25 A	
- 1	Mounting	PCB Mounting	
	PCB terminals	Require	
	Equivalent: OMRAN model G7L-2A-P	Require	
9	PCB mounting for relay in S/N 8	781-	Direct consider stadies of

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SERVICE OF

Specification of the electronics components

1. IC log112A

Packaging: SO-14

Supply Voltage, V+ to V- ±18V

Inputs ±18V

Input Current: ±10mA

Output Short-Circuit Current: Continuous Operating Temperature -40°C to +85°C Storage Temperature -55°C to +125°C

2. IRF 540 MOSFET

Packaging: TO-220AB

Drain-Source Volt (Vds): 100V Drain-Gate Volt (Vdg): 100V Gate-Source Volt (Vgs): 20V Drain Current (Id): 30A

Power Dissipation (Ptot): 150W

Type: N-Channel

3. CA3140

Packaging: PDIP

Supply Voltage, V+ to V- ±18V
Differential mode Input Voltage 8V
DC Input Voltage (V+ +8V to V- -0.5V
Input Current 1mA
Output Short-Circuit Duration Indefinite
Operating Temperature -55°C to +125°C
Junction Temperature +150°C
Lead Temperature (soldering, 10s) +300°C
Storage Temperature -65°C to +125°C

4. UC3843

Packaging: DIP UVLO Start 8.5 V

Maximum Duty Cycle: <100%

Start Up Current <1 mA

Operating Frequency: up to 500KHz

5. Transistor 2N3906

Packaging: TO-92

MAXIMUM RATINGS

Rating Value Unit

Collector – Emitter Voltage
Collector – Base Voltage
Emitter – Base Voltage
Collector Current – Continuous
Total Device Dissipation@ TA= 25°C
Derate above 25°C

40 V dc
40 V dc
5.0 V dc
200mA dc
5.0 mW/°C

Operating and Storage Junction Temperature Range –55 to +150°C

- 6. Zener 50V, 1 watt Packaging: DO-41 Tolerance ±2%
- 7. Zener 30V, 1 watt Packaging: DO-41 Tolerance ±2%
- 8. DPST Relay- NO Coil: 24V,

Contact capacity: 25 A

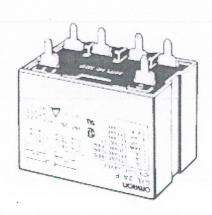
PCB terminals

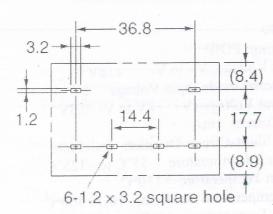
Equivalent: OMRAN model G7L-2A-P

PCB Mounting Holes

(Bottom View)

Tolerance: ±0.1 mm





9. PCB mounting for relay in S/N 8